

isc Silicon PNP Power Transistors

2SB656

DESCRIPTION

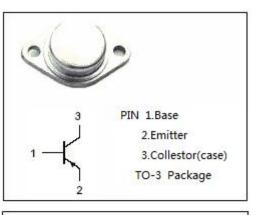
- Collector-Emitter Breakdown Voltage-: V_{(BR)CEO}= -160V(Min)
- High Power Dissipation-
- : Pc= 125W(Max)@Tc=25℃
- Complement to Type 2SD676
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

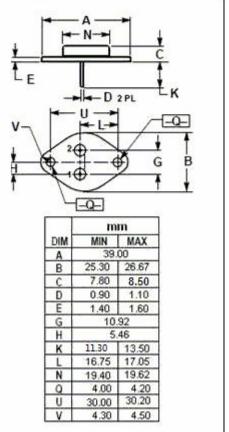
APPLICATIONS

• Designed for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-160	V	
V _{CEO}	Collector-Emitter Voltage	-160	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous -12		A	
I _{CM}	Collector Current-Peak -20		A	
Pc	Collector Power Dissipation @Tc=25℃125		W	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature	-55~150	°C	





isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -50mA; R _{BE} = ∞	-160			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -5mA; I _C = 0	-5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -6A; I _B = -0.6A			-2.5	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -1A; V _{CE} = -5V			-1.5	V
Ісво	Collector Cutoff Current	V _{CB} = -120V; I _E = 0			-0.1	mA
h _{FE-1}	DC Current Gain	I _C = -1A; V _{CE} = -5V	60		200	
h _{FE-2}	DC Current Gain	Ic= -6A; Vce= -5V	20			
f _T	Current-Gain—Bandwidth Product	I _C = -1A; V _{CE} = -5V		22		MHz

h_{FE} Classifications

В	С
60-120	100-200

NOTICE:

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